Development of "Large gas Electron Multiplier" (LEM) detectors for high gain operation in ultra-pure noble gasses

B. Baibussinov, G. Meng, *F. Pietropaolo*, S. Ventura, S. Centro.

R&D Proposal - INFN PD - GR. V Padova, 7 - 6 - 2006

# Outline

#### The basic idea:

- Macroscopic version of hole Gas Electron Multipliers (GEM's)
  - ~mm hole size in standard double-face Cu-clad Printed Circuit Board (PCB)
  - Characteristics & performance under investigation by several collaborations

#### Goals:

- Stable High gain (> 10<sup>4</sup> up to streamer regime) in pure noble gasses
  - quenching gas replaced by UV photon absorption in hole walls
- Good energy resolution
  - negligible charge loss due to electron diffusion and avalanche size (small wrt hole size)
- Direct readout of LEM electrodes
  - X-Y segmentation
- Possible applications:
  - Cryogenic double phase TPC's
    - low energy (~keV) event localization (Dark Matter, Solar Neutrinos)
  - High pressure TPC for medical imaging
    - R&D activity fully funded in PD by PRIN 2005
  - Photosensitive large area detectors, RICH
    - coupling with radiation conversion detectors (CsI photocathodes)

7 June 2006

### What is a LEM

- A thick GEM-like gaseous electron multipliers made of standard printed-circuit board perforated with sub-millimeter diameter holes, chemically etched at their rims
  - In-house fabrication using automatic micromachining
  - Self-supporting
  - Extremely resistant to discharges (low capacitance)
- First introduced within the ICARUS R&D group
  - for double phase noble gasses TPC's in the keV region
    - H. Wang, PhD Thesis, UCLA, 1999
    - L. Periale et al, 2000.
- Developed also as GEM alternative
  - Coarser resolution
  - Low rate physics (slower signals)
    - A. Rubbia et al.
  - Photo conversion detectors
    - Breskin et al.
    - Policarpo et al.



#### Standard GEM



LEM



7 June 2006

#### LEM: principle of operation

- Upon application of a voltage difference across the LEM, a strong dipole field E<sub>hole</sub> is established within the holes.
  - Electrons deposited by ionizing radiation in a conversion region above the LEM, or produced on a solid radiation converter, are drifting towards the LEM under E<sub>drift</sub> and are focused into the LEM holes by a strong electric field inside the holes.
  - Electrons are multiplied within the holes under the high electric field (~25-50 kV/cm)
  - Avalanche electrons are collected on the LEM bottom electrode (a fraction could also be further transferred to a collecting anode or to a second, possibly similar, multiplier element).
- Each hole acts as an independent multiplier.
  - A more favorable hole aspect ratio allows better avalanche confinement, reducing photon-mediated secondary effects.
  - This leads to higher gains in LEM wrt GEM with similar gas mixtures and to high-gain operation in a large variety of gases, including highly scintillating ones like pure noble gasses or CF4.

#### LEM: E-field, Avalanche

- Characteristics:
  - 100% transparency to incoming electrons
    - Full detection efficiency
  - Strong constant field well confined inside hole
    - Avalanche confinement, stable gain
  - Uniform field across hole diameter
    - Uniform multiplication factor, good resolution



- In pure Argon the development of the avalanche is well confined inside the hole (0.5 mm diameter)
  - At 1bar: avalanche lateral size (incl. diffusion) ~300µm
  - Higher pressure squeezes the avalanche size

Negligible charging-up of hole walls

## Preliminary study of LEM in Ar



#### Typical signals and Spectra (Fe<sup>55</sup>)

#### Pure Argon (1 bar)



Gain > 1000 Resolution ~ 30% FWHM (15-20 % expected)

## LEM gain (pure Argon)





- Gain behaviour
  - Exponential grow in uniform electric field (parallel plate chamber)

$$G = \exp(\alpha d)$$

- d = detector thickness
- α = Townsend coefficient (depends on E,p,d)
- Max gain
  - Increases with thickness
    - Geometrically reduced photon feedback
- Time stability
  - Guaranteed if no discharges
    - Far from brake-down voltage
  - Sudden degradation after several occasional break-down
    - hole walls carbonization

## High pressure gain (pure Argon)

Fe<sup>55</sup> source Cd<sup>109</sup> source LEM thickness 1.6mm LEM thickness 1.6mm -GAIN 2.3bar GAIN 1.9bar 1400 1200 GAIN 2.9bar GAIN 1.82bar GAIN 2.5bar GAIN 1.77bar GAIN 2.7bar GAIN 1.7bar GAIN 3.21bar 1200 1000 GAIN 1.6bar GAIN 3.41bar 1.5bai AIN GAIN 3.54bar 1 4bar ΔΙΝ 1000 800 GAIN 1.15bar GAIN 1bar GAIN Gain 800 600 600 400 400 200 200 Λ 2200 2400 2600 2800 3000 3200 3400 3600 4500 5000 3500 4000 5500 6000 Voltage (V) Voltage (V)

- LEM thickness optimization for high pressure operation
  - 2.4 mm: too high voltage for reasonable gain
  - 1.0 mm: too high photon feed-back; early appearance of discharges

# Gain scaling vs pressure and field



Gain behaviour

$$G = \exp(\alpha d)$$

 Townsend coefficient α well described by Rose-Kroff law

$$\alpha = Ap \exp(-Bp/E)$$

- d = detector thickness
- E = electric field
- p = pressure
- A,B = parameters depending on gas mixture
- Not very significant deviation from expectations in wide range of E,p,d
  - Easily predictable gain and break-down value for different LEM layout

### LEM with gas mixtures

Example: LEM photon detector with reflective CsI photocathode.



7 June 2006

### Open problems for further R&D

- Residual charging-up of holes walls due ions/electrons diffusion especially at high rate and residual photon feed-back in pure noble gasses, affecting:
  - Maximum Gain
  - Energy resolution
  - Time stability
- Possible fields of investigation:
  - LEM geometry (including multi-step)
    - To reduce diffusion effects
  - Electrodes oxidation
    - To minimize photon feed-back and electron extraction
  - Resistive electrodes
    - To improve "quenching" effect (RPC-like) and reach streamer mode gain
  - Needle-LEM
    - To avoid discharges and carbonization of LEM hole walls

#### **Resistive electrodes**

- Hybrid RPC concept:
  - Resistive layer "quenches" the electron avalanche
  - Vetronite holes "limit" the photon propagation and after pulses
- Goal
  - It Should allow gains up to streamer mode (maybe limited by photon feed-back through hole input)
- Disadvantages
  - Choice of resistive material critically depending on rate and gain (resistive materials from Quadrant Technology, ranging from 10<sup>5</sup> to 10<sup>15</sup> Ωcm, under investigation)

Preliminary results: Gain >> 10<sup>4</sup> easily reached



A charged particle entering the hole induces an avalanche, which develops into a spark. The discharge is quenched when all of the locally (~1 hole) available charge is consumed. Photons are blocked by vetronite walls.



The discharged area recharges slowly through the high-resistivity plates.



 Coupling of a LEM with a needle array and oxided-Cu (or resistive) layer



- Advantages
  - much longer discharge path along hole walls
  - Ion trajectories ending onto electrodes (no charging-up)
  - More efficient photon trapping

- Disadvantages
  - Critical adjustment of needle height and shape: affecting gain uniformity



Top electrode

Preliminary results: Gain >> 10<sup>4</sup> easily reached Poor resolution (~50%FWHM)

#### Vetronite

## **Specific applications**

- Optimization of LEM's in pure Noble gasses could lead to improvements in several detection fields
  - Avoiding quenching gas could allow
    - Higher yields
    - More stable performance (less degradation due to aging effects)
- Moreover, segmented LEM, cabable of x,y localization, could find direct applications in:
  - High pressure Xenon TPC's
    - Replacements of wires and strips in CARDIS chamber for fast medical imaging:
      - Better resolutions
      - Higher time stability
      - No polymerization of quenching gas
    - See PRIN 2005
  - Large area UV photodetectors
    - Coupling with CsI photocathodes
    - Reflective CsI coating for UV scintillation collection in TPC's



#### Xenon TPC's (CARDIS-PRIN2005) for fast medical imaging

- Photoelectic e<sup>-</sup> from ~10<sup>2</sup> KeV γ's (Tantalium, Tecnetium)
  - Moderate gain required: 10<sup>2</sup> 10<sup>3</sup>
  - High density (pressure >6 bar): high absorption efficiency
  - Good event localiziation: limited e<sup>-</sup> diffusion allows mm size pixel
- Compton rejection
  - Requirements: good energy resolution.
- Segmented LEM could match detector requirements:
  - Design with ~mm segmentation seems at reach
  - Gain under high pressure under investigation
    - Needle-LEM could be used to increase gain
- Double phase cryogenic TPC's (Ar, Xe)
  - Similar requirements
    - High pressure = high density in cryogenic gas phase



V. Peskov et al. (CERN)

#### Large area UV photosensitive detectors



#### LEM with resistive coating P.Fonte et al.

#### Large area UV photosensitive detectors



7 June 2006

higher gains are possible with resistive coating



### Partecipanti, tempi, richieste

#### valutazione preliminare

- Partecipanti:
  - Padova
    - B. Baiboussinov
    - S. Centro
    - F.Pietropaolo (Resp.)
    - S. Ventura
    - G. Mena
  - LNF
    - G. Mannocchi
    - L.Periale
    - P. Picchi
  - CFRN
    - R. De Oliveira
    - A. Di Mauro
    - P. Martinengo
    - V. Peskov
- Richieste ai servizi:
  - 2 mesi uomo Lab. Elettronico
  - 2 mesi uomo Officina Meccanica
  - 1 mese uomo Ufficio Tecnico
- Trasferte:
  - Interne: 3 mesi uomo (metabolismo + tests a LNL)
  - Estere: 1 mese uomo (progettazione PCB e deposizioni Csl)

- Durata: 24 Mesi
- Milestones:
  - Primo anno: Prototipi piccola scala (10x10 cm<sup>2</sup>):
    - ottimizzazione layout LEM, LEM+needles, LEM resistive .
      - Guadaqno
      - Risoluzione .
      - Stabilita temporale
      - Accoppiamento con fotoconvertitori per VUV
  - Secondo anno: LEM di medie dimesioni (30x30 cm<sup>2</sup>):
    - Readout segmentato per:
      - Imaging medicale in Xenon ad alta pressione (CARDIS)
      - Fotorivelatori a grande area
      - LAr-TPC doppia fase
- Previsioni di spesa:
  - Consumo (totale ~19000 €):
    - Forfait workshop PCB CERN (materiale + lavorazione) • ~7000€
    - Fornitura Argon e Xenon per test ~ 5000 €
    - Fornitura campioni materiale resistivo ~3000 €
    - Deposizione CsI al CERN (materiale + lavorazione) ~4000€